NSN 5961-01-374-5996

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-374-5996 **Inclosure Material:** Metal **Overall Length:** 1.855 inches **Overall Diameter:** 0.597 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Thready Qty Per Inch (tpi): **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 700.0 repetitive peak reverse voltage and 840.0 nonrepetitive peak reverse voltage and 700.0 repetitive peak off-state voltage **Current Rating Per Characteristic:** 1000.00 amperes forward current, dc nanoamperes and 63.00 amperes drain current pascal and 40.00 amperes forward current, dc megahertz **Power Rating Per Characteristic:** 2.0 watts any acceptable universal **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnpn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 uninsulated wire lead w/terminal lug and 1 tab w/wire lead and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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